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- 1. A method of manufacturing a liquid crystal display (LCD) device, comprising: forming a photo-sensitive layer over a substrate;
- forming a photo-insensitive layer over the photo-sensitive layer;
 exposing a portion of the photo-sensitive layer via a photo-mask to a radiation source;
 and
 contacting the portion of the photo-sensitive layer using a developing solution.
- 2. The method of claim 1, wherein said contacting dissolves the portion of the photosensitive layer and removes the portion of the photo-insensitive layer overlying the portion of the photo-sensitive layer together.
 - 3. The method of claim 1, wherein the photo-insensitive layer is formed of photo-insensitive resin.
 - 4. The method of claim 3, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
 - 5. The method of claim 1, wherein the radiation source is electron beam radiation, x-ray radiation, or ultraviolet radiation.
 - 6. The method of claim 1, wherein the developing solution includes an alkaline solution.
 - 7. The method of claim 6, wherein said alkaline solution is TMAH.
 - 8. The method of claim 1, wherein the photo-sensitive layer is formed of photo-sensitive resin.
 - 9. The method of claim 8, wherein the photo-sensitive resin is selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.

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- 10. The method of claim 1, wherein the thickness of the photo-sensitive layer is between approximately 0.1 and 8 μ m.
- The method of claim 1, wherein the thickness of the photo-insensitive layer is
 between approximately 0.1 and 8 μm.
 - 12. The method of claim 1, wherein the thickness ratio of the photo-insensitive layers to the total thickness of the photo-sensitive layer and photo-insensitive layer is not more than approximately 50%.
 - 13. The method of claim 1, wherein the dielectric constant of the photo-sensitive layer is between approximately 2.5 and 4.0.
 - 14. The method of claim 1, wherein the dielectric constant of the photo-insensitive layer is between approximately 1.5 and 3.5.
 - 15. The method of claim 1, wherein the combined dielectric constant of the photosensitive layer and the photo-insensitive layer is between approximately 1.5 and 3.5.
 - 16. The method of claim 1, wherein said forming the photo-insensitive layer and said forming the photo-sensitive layer are performed consecutively.
 - 17. The method of claim 1, further comprising, curing the photo-insensitive layer and the photo-sensitive layer at the same time.
 - 18. The method of claim 17, further comprising:
 forming a transparent electrode layer overlying the resulting structure.
- 19. A method of manufacturing a liquid crystal display (LCD) device, comprising:

 forming a gate bus line over an insulating substrate;

 forming a gate insulator over the gate bus line;

 forming a drain electrode over the gate insulator;

 forming a photo-sensitive layer over a substrate;

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forming a photo-insensitive layer over the photo-sensitive layer;
exposing a portion of the photo-sensitive layer via a photomask to a radiation source,
contacting the portion of the photosensitive layer using a developing solution through
the photo-insensitive layer to remove the portion of the photo-sensitive layer and an
immediately overlying portion of the photo-insensitive layer;

curing the photo-insensitive layer and the photo-sensitive layer at the same time; and forming a transparent electrode layer overlying the resulting structure.

- 20. The method of claim 19, wherein the transparent electrode layer includes indium tin oxide (ITO).
 - 21. The method of claim 20, the insulating substrate is formed of transparent material.
 - 22. The method of claim 19, wherein photo-insensitive layer is formed of photo-insensitive resin.
 - 23. The method of claim 21, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
 - 24. The method of claim18, wherein the developing solution comprises an alkaline solution.
 - 25. The method of claim 24, wherein said alkaline solution is TMAH.
 - 26. The method of claim 18, wherein the photo-sensitive layer is formed of photo-sensitive resin.
- 27. The method of claim 26, wherein the photo-sensitive resin is one selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.

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- The method of claim 19, wherein the thickness of the photo-sensitive layer is 28. between approximately 0.1 and $8~\mu m$ and the thickness of the photo-insensitive layer is between approximately 0.1 and 8 µm.
- The method of claim19, wherein the thickness ratio of the photo-insensitive layers to 29. 5 the total thickness of the photo-sensitive layer and photo-insensitive layer is not more than approximately 50%.
- The method of claim 19, wherein the dielectric constant of the photo-sensitive layer is 30. between approximately 2.5 and 4.0. 10
 - The method of claim 19, wherein the dielectric constant of the photo-insensitive layer 31. is between approximately 1.5 and 3.5.
 - The method of claim 19, wherein the combined dielectric constant of the photo-32. sensitive layer and the photo-insensitive layer is between approximately 1.5 and 3.5.
 - The method of claim 19, wherein the photosensitive layer has a thickness of 33. approximately 1.5 μm and photo-insensitive layer has a thickness of approximately 1.5 μm.
 - 34. A liquid crystal display (LCD) device comprising:
 - an insulating substrate,
 - a gate bus line formed overlying the substrate;
 - a gate insulating layer formed over the gate bus line;
 - a drain electrode formed over the gate insulating layer; and
 - a multi-layer interlayer insulator formed overlying the drain electrode, the multi-layer interlayer insulator having a through hole.
- The LCD device of claim 34, further comprising: 35. 30
 - a pixel electrode formed over the multi-layer interlayer insulator including the through hole.

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- 36. The LCD device of claim 34, wherein the multi-layer interlayer insulator comprises a photo-sensitive resin and a photo-insensitive resin overlying the photo-sensitive resin.
- 37. The LCD device of claim 36, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
 - 38. The LCD device of claim 36, wherein the photo-sensitive layer is formed of one selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.
 - 39. The LCD device of claim 34, wherein the thickness of the photo-sensitive layer is between approximately 0.1 and $8 \mu m$.
 - 40. The LCD device of claim 34, wherein the thickness of the photo-insensitive layer is between approximately 0.1 and 8 μm .
 - 41. The LCD device of claim 34, wherein the thickness ratio of the photo-insensitive layers to the total thickness of the photo-sensitive layer and photo-insensitive layer is not more than approximately 50%.
 - 42. The LCD device of claim 34, wherein the dielectric constant of the photo-sensitive layer is between approximately 2.5 and 4.0.
- 25 43. The LCD device of claim 34, wherein the dielectric constant of the photo-insensitive layer is between approximately 1.5 and 3.5.
 - 44. The LCD device of claim 34, wherein the combined dielectric constant of the photosensitive layer and the photo-insensitive layer is between approximately 1.5 and 3.5.
 - 45. The LCD device of claim 34, wherein the photosensitive layer has a thickness of approximately 1.5 μm and photo-insensitive layer has a thickness of approximately 1.5 μm .

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- 46. A liquid crystal display (LCD) device comprising:
 - a transparent insulating substrate,
 - a gate bus line formed overlying the substrate;
 - a gate insulating layer formed over the gate bus line;
 - a drain electrode formed over the gate insulating layer;
- a multi-layer interlayer insulator formed overlying the drain electrode, the multi-layer interlayer insulator having a through hole; and
- a transparent electrode formed over the multi-layer interlayer insulator including the through hole,

wherein the multi-layer interlayer insulator comprises a photo-sensitive resin and a photo-insensitive resin overlying the photo-sensitive resin.

- 47. The LCD device of claim 46, wherein the photo-insensitive resin is selected from the group consisting of photo-insensitive PFCB, photo-insensitive BCB, photo-insensitive polyimide and photo-insensitive SOG.
- 48. The LCD device of claim 46, wherein the photo-sensitive layer is formed of one selected from the group consisting of photo-sensitive acrylic resin, photo-sensitive BCB, photo-sensitive PFCB and photo-sensitive polyimide.

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